

**AMENDMENTS TO THE CLAIMS:**

This listing of claims will replace all prior versions and listings of claims in the application:

Listing of Claims:

1-19. (Canceled).

20. (Currently amended): A photodetector comprising:  
an active zone for detecting optical radiation; and  
a structure arranged on said active zone, intended for optically coupling the  
optical radiation, said structure combining the properties of coupling gratings and Bragg  
gratings and having a defect which, from an incident wave, makes it possible to obtain a  
plasmon wave which is both coupled and localized in the active zone, said active zone  
having dimensions which are small compared to those of said structure,  
wherein said active zone has an elongate shape and said structure is composed  
of grooves which are mutually parallel and parallel to the length of the active zone;

~~The photodetector as claimed in claim 19,~~ wherein said structure is produced in a layer of at least one dielectric material which is transparent in the spectral range of the optical radiation, said layer comprising a substantially plane lower face in contact with the active zone and an upper face comprising the grooves of the structure, said face being covered with a metal film, and in that the optical thickness of said layer separating the lower face from the upper face along an axis (Ox) perpendicular to the direction of the grooves and parallel to the plane of the lower face varies as the superposition of a coupling grating whose pitch has a first spatial frequency and a second grating whose pitch has a second spatial frequency that is two times the first spatial frequency and which has a central spatial defect.

21. (Previously Presented): The photodetector as claimed in claim 20, wherein the layer constituting the structure is made from an isotropic dielectric material, and the profile of each groove along the axis perpendicular to the direction of the grooves is composed of mutually parallel plane facets with different heights.

22. (Previously Presented): The photodetector as claimed in claim 20, wherein the layer constituting the structure is made from a material composed of mutually parallel alternate layers of equal thickness and a central layer of double thickness, said layers alternately comprising a first material having a first permittivity and a second material having a second permittivity, the plane of the layers being perpendicular to the plane of the lower face, and in that the profile of each groove along the axis perpendicular to the direction of the grooves is composed of regular crenellations with a pitch two times greater than the thickness of the alternate layers.

23. (Previously Presented): The photodetector as claimed in claim 20, wherein the optical thickness of said layer separating the lower face from the upper face varies along an axis (Ox) perpendicular to the direction of the grooves and parallel to the plane of the lower face, whose origin is centered on the center of the grating, as a function which is the sum or the difference of:

a first function which is proportional to the sign function of the cosine function of the distance from the origin of said axis and has a period equal to that of the pitch of the grooves; and

a second function which is proportional to the sign function of the cosine function of the absolute value of the distance from the origin of said axis and has a period equal to half that of the pitch of the grooves, said second function being phase-shifted by one half-period with respect to the first function.

24. (Previously Presented): The photodetector as claimed in claim 20, wherein the optical thickness of said layer separating the lower face from the upper face varies along an axis (Ox) perpendicular to the direction of the grooves and parallel to the plane

of the lower face, whose origin is centered on the center of the grating, as a function which is the sum or the difference of:

a first function which is proportional to the sign function of the sine function of the distance from the origin of said axis and has a period equal to that of the pitch of the grooves; and

a second function which is proportional to the sign function of the cosine function of the absolute value of the distance from the origin of said axis and has a period equal to half that of the pitch of the grooves, said second function being phase-shifted by one half-period with respect to the first function.

25. (Currently amended): The photodetector as claimed in ~~one of~~ claim 23, wherein the proportionality coefficient of the first function is two times that of the second function.

26. (Previously Presented): The photodetector as claimed in claim 20, wherein the pitch of the first grating of the structure is approximately equal to half the average wavelength of the incident radiation divided by the average optical index of the structure.

27. (Currently amended): The photodetector as claimed in claim 20 ~~claim 18~~, wherein that said two-dimensional structure is composed of patterns with substantially identical dimensions, in that the active zone is centered on said structure and in that the dimensions of the active zone are substantially equal to the average dimensions of the patterns.

28. (Previously Presented): The photodetector as claimed in claim 27, wherein the structure is produced in a layer of at least one dielectric material which is transparent in the spectral range of the optical radiation, said layer comprising a substantially plane lower face in contact with the active zone and an upper face

comprising the patterns of the structure, said face being covered with a metal film, the optical thickness of said layer separating the lower face from the upper face varying:

along a first axis parallel to the plane of the lower face, as at least one first grating whose pitch has a first spatial frequency;

along a second axis perpendicular to the first axis and parallel to the plane of the lower face, as at least one second grating whose pitch has the same first spatial frequency; and

along an oblique third optical axis at 45 degrees to the previous two, as at least one third grating whose pitch has a second spatial frequency equal to half the first spatial frequency.

29. (Previously Presented): The photodetector as claimed in claim 28, wherein, when the layer constituting the structure is made from an isotropic dielectric material, each pattern is composed of mutually parallel plane facets with different heights.

30. (Previously Presented): The photodetector as claimed in claim 29, wherein the optical thickness of said structure separating the lower face from the upper face varies along two mutually perpendicular axes, which are parallel to the plane of the lower face and whose common origin is centered on the center of the structure, as a function which is the sum or the difference of:

a first function which is proportional to the sign function of a first cosine function of the absolute value of the distance from the origin proportional to the sign function of the cosine function first axis, said first cosine function being phase-shifted by plus or minus 90 degrees with respect to the origin;

a second function which is proportional to the sign function of the cosine function of the absolute value of the distance from the origin along the axis perpendicular to said first axis and has a period identical to that of the first function, said second cosine function being phase-shifted by plus or minus 90 degrees with respect to the origin;

a third function which is proportional to the sign function of the sine function of the difference between the distances to the origin along the first axis and the second axis.

31. (Previously Presented): The photodetector as claimed in claim 27, wherein the dimensions of the patterns of the structure are approximately equal to half the average wavelength of the incident radiation divided by the average optical index of the structure.

32. (Currently amended): The photodetector as claimed in claim 20 ~~claim 18~~, wherein the active zone is surrounded by an optically passive zone with dimensions substantially equal to those of the structure.

33. (Previously Presented): The photodetector as claimed in claim 32, wherein the active zone is a quantum well structure.

34. (Previously Presented): A photosensitive matrix comprising a plurality of photodetectors organized in rows and columns, wherein that said photodetectors are as claimed in one of the preceding claims.

35. (Currently amended): The photodetector as claimed in ~~one of~~ claim 24, wherein the proportionality coefficient of the first function is two times that of the second function.